



PAPER

Theoretical investigations of optoelectronic and transport properties of halide based K_2YAuX_6 ($X = Cl, Br$) double perovskitesGhulam M Mustafa^{1,*}, Raja Waqar², Sadaf Saba³, N A Noor⁴, Zahid Farooq¹, Muhammad Imran⁵, R B Behram⁶ and Yousef Mohammed Alanazi⁷¹ Department of Physics, Division of Science and Technology, University of Education, Lahore, Punjab 54770, Pakistan² Electrical and Biological Physics, Krangwon University, Seoul, 01897, Republic of Korea³ Department of Physics, Government College University, Faisalabad, 38040, Pakistan⁴ Department of Physics, RIPHAH International University, Campus Lahore, Pakistan⁵ Department of Physics, Government College University, Lahore, Pakistan⁶ Department of Physics, AIOU, Islamabad, Pakistan⁷ College of Engineering, Chemical Engineering Department, King Saud University Riyadh, Saudi Arabia

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E-mail: dr.ghulam.muhammad@ue.edu.pk**Keywords:** double perovskites, tolerance factor, enthalpy of formation, band structure**Abstract**

Intriguing optoelectronic and transport properties with huge compositional range and structural stability make double perovskites interesting for energy harvesting technologies. Here we theoretically investigate the structural, optical, mechanical, and transport properties of K_2YAuX_6 ($X = Cl, Br$) double perovskites using the WIEN2K code. Based on the calculated values of the tolerance factor and enthalpy of production, the thermodynamic and structural stability is affirmed. The ductile nature of these compositions is revealed in the computation of Poisson's ratio (>0.26) and Pugh's (1.75) ratio. The involvement of s-states of K, p-states of Cl/Br, and d-states of Y and Au in the formation of valence and conduction band edges is exhibited from the density of state plots. Using the Tran-Blaha mBJ potential and spin-orbital coupling, the energy bandgap value for K_2YAuCl_6 and K_2YAuBr_6 is reported as 3.20, and 2.70 eV, respectively, which is suitable for the fabrication of light-emitting diodes. Optical behavior is further explored regarding complex dielectric constant, refractive index, optical conductivity, optical loss, and absorption factor. The small value of thermal conductivity with large value of electrical conductivity, Seebeck coefficient, power factor, and figure of merit revealed the potential of these materials for the fabrication of light-emitting diodes and thermoelectric generators.

1. Introduction

Efficient utilization of energy is a crucial aspect of modern civilization and its evolution [1]. Most of the energy we use comes from the burning of solid fuels. This usage of fossil fuels contains major issues such as climate change and global warming [2]. It is worth noticing that only one-third of generated energy is effectively utilized, whereas rest two-thirds is wasted as heat [3]. So, there is an urgency to develop such devices that can proficiently convert this wasted heat into useful energy [4]. Developing a device that can convert the wasted heat of automobiles, residential, and industrial heating processes to electrical energy is highly desired [5–7]. Thermoelectric (TE) materials can transform wasted heat into electrical energy and gained considerable attention. The Seebeck effect is a key parameter in analyzing the efficiency of TE materials [8, 9]. The promising solid-state nature of TE materials make them flexible in operational integration [10]. The efficiency of these materials is calculated using the expression $ZT = S^2\sigma T/\kappa$. In this expression, T , σ , κ , and S are absolute temperature, electrical, thermal conductivity, and Seebeck coefficient, respectively [11, 12]. The motion of electron in response to temperature gradient constitute to the electronic part of thermal conductivity (κ_e) and temperature dependent lattice vibration is called lattice thermal conductivity (κ_l) combinedly define the net thermal conductivity of the material. For better thermoelectric performance, the electrical conductivity and

Seebeck coefficient should be large and thermal conductivity should be small [13, 14]. The fundamental issue regarding improvement of thermoelectric performance is the implicit nature of involving quantities which leads to the interesting fact that increasing one quantity reduces the other [15].

Most of the thermoelectric materials in service are chalcogenides like Bi_2Se_3 , Bi_2Te_3 , Sb_2Te_3 , and Zn_4Sb_3 [16]. The major heat produces from several sources is at more than 900 K temperature, where these materials are decomposed or oxidized [17]. Thus halide-based double perovskite materials are strong candidates for high-temperature thermoelectric applications owing to their low cost, easy availability of constituent elements, and thermal stability at high temperature [18]. The general formula of these materials is $\text{A}_2\text{B}'\text{B}''\text{X}_6$. In this expression, A is usually an alkali metal, B' and B'' are transition metals, and X is a halide anion [19]. In the crystal structure of double perovskites (DP) there are three types of cationic arrangement of B-site atoms i.e., layered, rock salt, and random, which can be distinguished based on the ordering of $\text{B}'\text{X}_6$ and $\text{B}''\text{X}_6$ octahedra [20]. This different arrangement of octahedra generates different geometry and thus, different space groups. The space group belonging to the random arrangement of octahedra is $\text{Pm}\bar{3}m$ [21]. In this arrangement, A-site divalent atoms with coordinates (0, 0, 0) occupy the corner positions, whereas tetravalent B' and B'' occupy the body-centered position (1/2, 1/2, 1/2) whereas halide ions take a face-centered positions (0, 1/2, 1/2). In rock salt arrangement, $\text{B}'\text{X}_6$ and $\text{B}''\text{X}_6$ octahedra arrange alternately in three-dimensional space and thus give birth to three different space groups: P4/nmc , $\text{Fd}\bar{3}m$ and I4/m [22–24]. The layered-type structure of DP is the least common and rarely studied in which $\text{B}'\text{X}_6$ and $\text{B}''\text{X}_6$ octahedra are alternatively arranged in one dimension [25]. The stability of developed double perovskites can be predicted by computing the Goldschmidt tolerance factor. For stable double perovskites, the value of T_F should be in the range of 0.9 to 1.4 [26].

Double perovskites have huge structural flexibility and thus can accommodate various cations at cation sites, thus giving them a wide range of applications. The DP with halides as an anion were broadly studied for their optoelectronic and thermoelectric applications [27, 28]. For instance, Kangsabanik *et al* conducted an intuitive analysis of double perovskites and proposed that double perovskites effectively replace simple perovskites because of their better light-to-electricity conversion efficiency with improved stability [29]. This statement received further support from the study of Chakraborty *et al* who suggested that DPs are taking more place in the photovoltaic market due to their higher stability and scalability [30]. In addition, Slavney *et al* synthesized $\text{Cs}_2\text{AgBiBr}_6$ DPs and studied its optoelectronic properties, and observed that this composition has an indirect bandgap nature with an appropriate bandgap value [31]. Similarly, Volonasik *et al* theoretically and experimentally evaluated $\text{Cs}_2\text{InAgCl}_6$ composition and observed its bandgap value of 3.3 eV. They proposed that this bandgap can be modified by suitable adjusting the halide ions [32]. The compositions with wide bandgap having indirect nature are not suitable for solar cell applications, and recently, Meng *et al* claimed that due to the presence of inversion symmetry, indirect bandgap compositions are not optically transition free [33].

However, among the available compositions, $\text{Cs}_2(\text{Ti, In})^{+1}(\text{Bi, Sb})^{+3}\text{X}_6$ are the rare compositions that evolved due to extensive research work on double perovskites. During the comprehensive literature survey, we did not come across any study on the thermoelectric characteristics of K_2YAuX_6 (Cl, Br); thus, we planned to explore the potential of these double perovskite compositions for emerging technological applications thus, in this study, we elaborated the structural, optoelectronic and thermoelectric applications of these compositions and we believe that this writing would add a piece of substantial information in the existing knowledge regarding DPs and would unveil the underlying mechanism in working of thermoelectric devices.

2. Computational

Within the WIEN2K computational package, the full-potential linearized augmented plane wave method (FP-LAPW) developed on the basis of density functional theory (DFT) was implemented to compute the optoelectronic and thermoelectric properties of double perovskites [34–36]. The electronic structure was checked by the optimization of the cubic phase and space group as well as ground state lattice constant and bulk modulus. The ground state behavior was calculated using the Birch-Murnaghan equations of state that used energy released during the optimization process [37]. The PBEsol-GGA measured the ground state parameters accurately and mBJ potential generate bandgap values close to experimental value. In $\text{K}_2\text{YAuCl/Br}_6$ DPs, the electronic bandgaps were estimated using TB-mBJ potential [38, 39]. The values of the product of R_{MT} and K_{max} , G_{max} , and k-mesh were kept constant at 8, 16, and 1000. To get more reliable value of bandgap, k-mesh was made denser to by increasing the number of k-points. These optical factors were calculated with the help of the Kramer-Kronig relation [40]. For different types of materials, the BoltzTraP code of classical transport theory has been used to explore the thermoelectric factors, that's why we also utilized this approach here [41, 42].

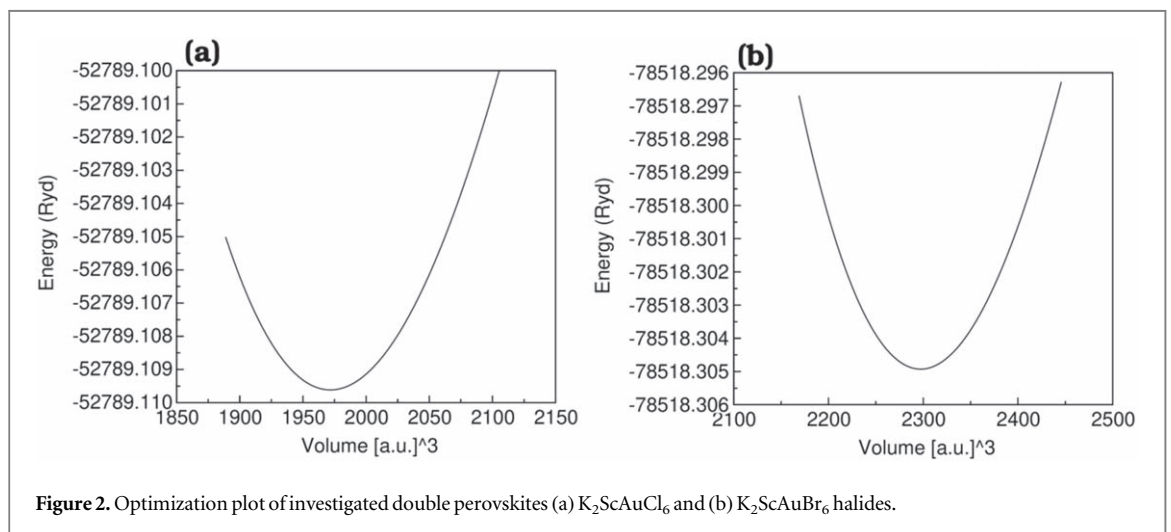
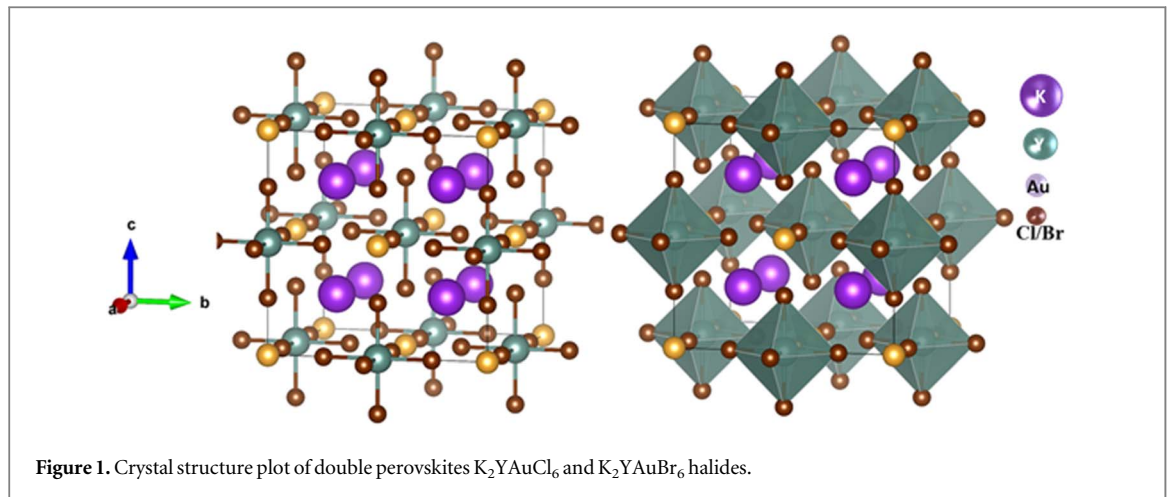


Table 1. Calculated values of lattice constant $a_o(\text{\AA})$ compared with existing work, bulk modulus $B_o(\text{GPa})$, Enthalpy of formation (ΔH_f) and elastic parameters of K_2YAuCl_6 and K_2YAuBr_6 halides.

Parameters	K_2YAuCl_6	K_2YAuBr_6
	PBEsol-GGA	PBEsol-GGA
$a_o(\text{\AA})$	10.53	11.08
Other work	10.74 ^a	11.28
$B_o(\text{GPa})$	35.52	30.03
ΔH_f	-2.08	-1.56
C_{11}	86.54	59.99
C_{12}	10.89	15.12
C_{44}	7.65	8.07
B	35.44	30.07
G	15.29	12.33
Y	40.11	32.54
B/G	2.31	2.43
ν	0.31	0.31
A	0.20	0.35

^a [46].

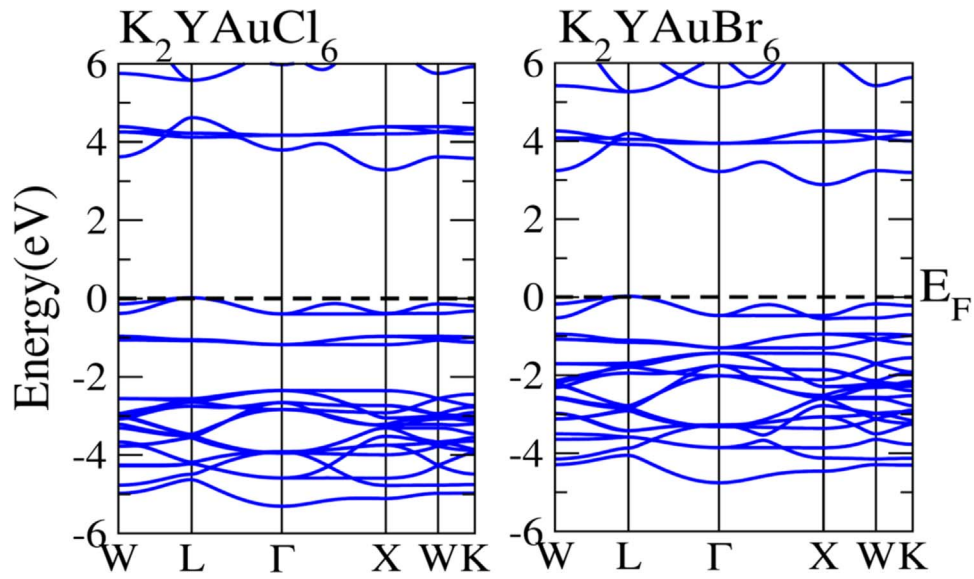


Figure 3. Calculated electronic band structure for K_2YAuCl_6 and K_2YAuBr_6 halides.

3. Discussion of results

3.1. Structural characteristics

The crystal structure of the DPs ($A_2BB'X_6$) is almost the same as that of the single perovskites but with a double lattice parameter value. They have $Fm\bar{3}m$ space group. The Wyckoff positions of atoms in K_2YAuCl/Br_6 are: K atoms at 8c-site, Y atoms at 4a-site, Au atoms at 4b-site and Cl/Br atoms at 24e-site. The K and Y atoms are monovalent cations, and Au is trivalent while Cl/Br ions have oxidation state of -1 [43]. Figure 1 depicts the unit cell of K_2YAuCl/Br_6 DPs where it can be seen that purple-colored and green-colored balls correspond to K and Y atoms whereas golden and brown-colored balls correspond to Au and X atoms respectively. The energy-volume optimization graph of these DPs is shown in figure 2. The structural stability of K_2YAuCl_6 and K_2YAuBr_6 can be probed by calculating the tolerance factor (t_G) and thermodynamical stability can be checked by the calculation of enthalpy of formation (ΔH_f). The former term can be calculated using the atomic radii of all the atoms while the later term is measured using the energies of all the atoms. The expressions to compute both terms are given here [44]:

$$t_G = (r_K + r_X) / \sqrt{2} (r_B + r_X) \quad (1)$$

$$\Delta H_f = E_{Total}(K_a Y_b Au_c X_d) - aE_K - bE_Y - cE_{Au} - dE_X \quad (2)$$

Here r_K and r_X represent the atomic radii of K and X atoms and r_B represents the average atomic radii of Y and Au atoms. For stable structures, the t_G value reaches 1 as the range of t_G value for stable structures is between 0.8 to 1.4 [45]. The DPs under observation are structurally stable because the t_G values for K_2YAuCl_6 and K_2YAuBr_6 are 0.92 and 0.94, as listed in table 1, which lie within the stable range structures. The thermodynamical stability can be computed using equation (2) given above where $E_{Total}(K_a Y_b Au_c X_d)$ is the overall energy of the composition [45] and the terms E_K , E_Y , E_{Au} and E_X give energies of K, Y, Au and X atoms respectively. Every element has a different number of atoms that are represented by the coefficients a, b, c and d.

The value of ΔH_f for K_2YAuCl_6 and K_2YAuBr_6 are -2.08 eV and -1.56 eV, which are negative, so both compositions are thermally stable. Plotting the energy volume optimization graph leads to determine the optimized lattice parameters and bulk modulus value. All these computed parameters are presented in table 1, which show that lattice parameter (a_0) increased from 10.53 to 11.08 Å, and bulk modulus decreased from 35.52 to 30.03 GPa when Cl in the structure is replaced with Br. This variation in lattice parameter and bulk modulus is associated with relative ionic sizes of the host and substituent.

3.2. Mechanical characteristics

To probe the mechanical response of any material it is set under the mechanical stress and mechanical properties are determined in terms of elastic constants, which are fourth-order tensors. To compute these constants, the tensor matrix formed by the non-linear differential equations is solved. For the calculation of the mechanical response of cubic materials, one needs C_{11} , C_{12} , and C_{44} whose calculated values are given in table 1. The born stability criteria is verified based on the numerical values of these constants [47]. Here the substitution of Cl with

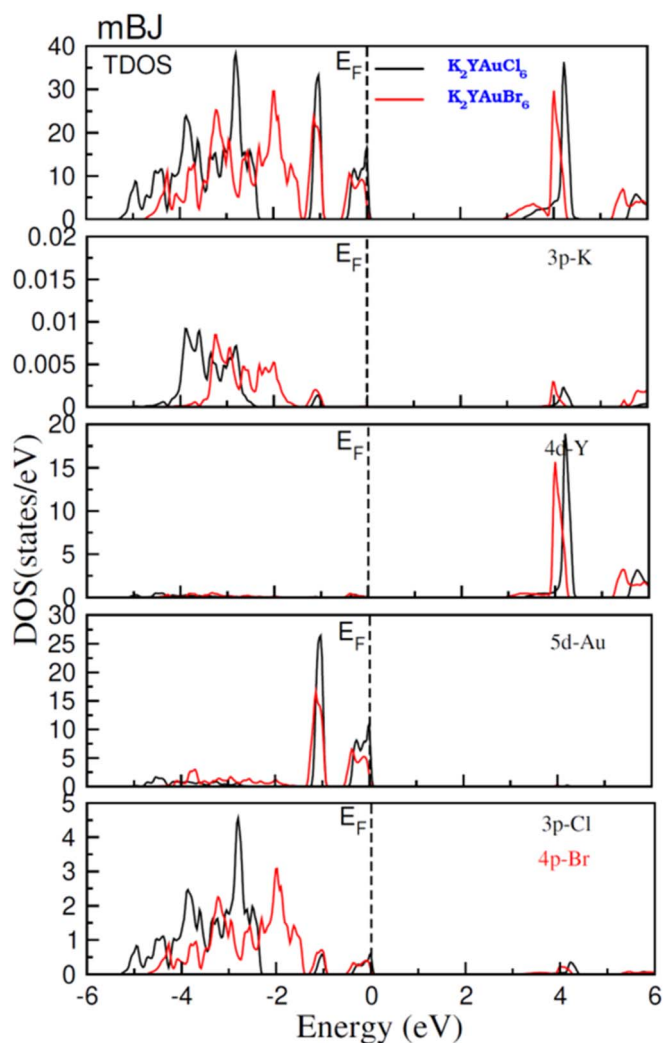


Figure 4. Calculated total density of states (DOS) along with partial DOS for K_2YAuCl_6 and K_2YAuBr_6 halides.

Br causes the increase in lattice constant, which reduces the tensile strength and thus leads to the reduction in elastic modulus. The numerical values of these elastic moduli play a deterministic role in evaluating the material's brittle or ductile nature. Based on these modulus of elasticity values, two key parameters called Poisson's ratio (ν) and Pugh ratio (B/G) were computed. The realization of the ductile nature of the material is ascertained if the value of $B/G > 1.75$ or $\nu > 0.26$. In the current investigation, the value of G/B is 2.31 and 2.43 for K_2YAuCl_6 and K_2YAuBr_6 , whereas the value of ν is 0.31 for both compositions, confirming the ductile nature of under study materials [48].

In addition to calculating the elastic parameters, another exciting parameter called anisotropy constant (A) was also calculated, determining a fascinating aspect of the material. Anisotropy is one of the key features of crystalline materials where they give different response in different directions to any external stimulus [49]. Isotropic material is distinguished from anisotropic material from the value of their anisotropic constant which is 1 for isotropic materials. Any deviation from the unitary value indicates the anisotropic behavior of the material. The value of anisotropic constant for K_2YAuCl_6 and K_2YAuBr_6 is 0.20 and 0.35, respectively, which exhibited that K_2YAuCl_6 is more anisotropic as compared to K_2YAuBr_6 .

3.3. Electronic characteristics

To ascertain the suitability of any material for optoelectronic devices, it is essential to map its bandgap structure. To probe the optoelectronic response of these double perovskites, we evaluated the electronic band structure using mBJ+SOC potential which is plotted in figure 3 [50]. The plotting of electronic band energy against different symmetry points revealed that the valence band maxima and conduction band minima lie at L, X-symmetry points respectively, exhibiting the indirect bandgap nature of these compositions [51]. The bandgap value for K_2YAuCl_6 is found to be 3.20 eV, which reduces to 2.70 eV when Cl is replaced with Br. This reduction in bandgap value is attributed to the larger atomic number and larger atomic size [52].

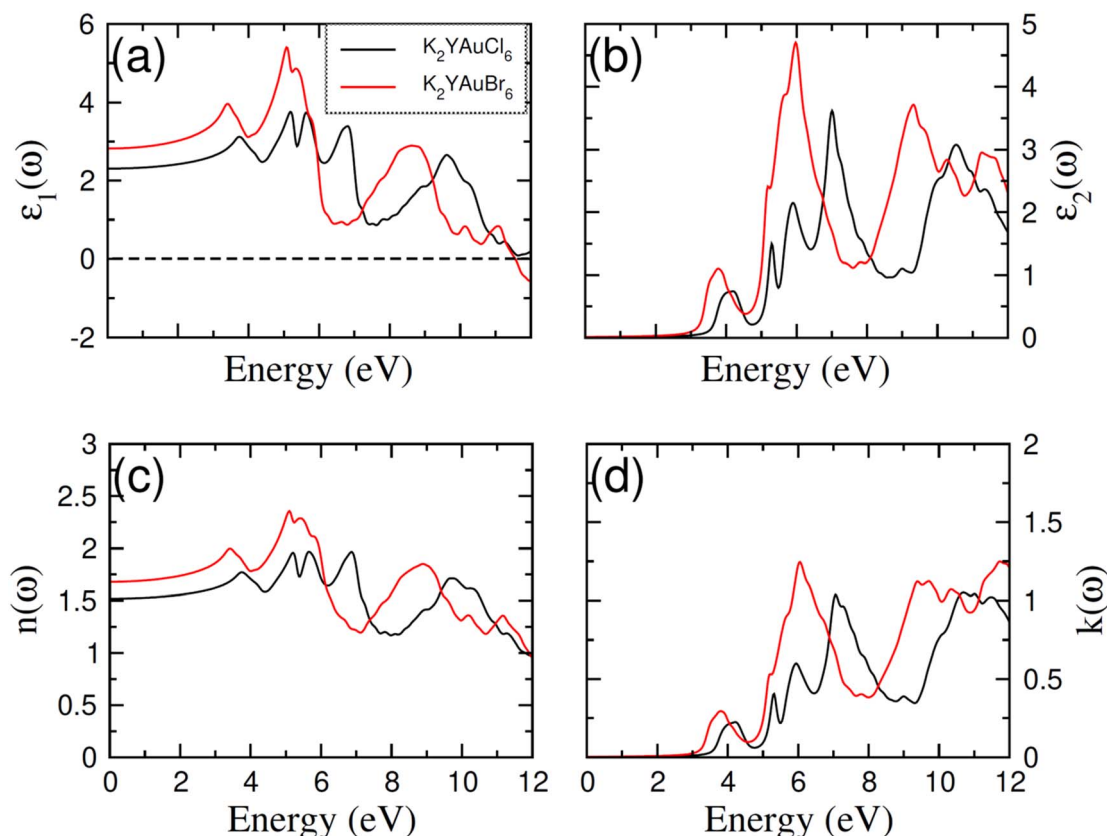
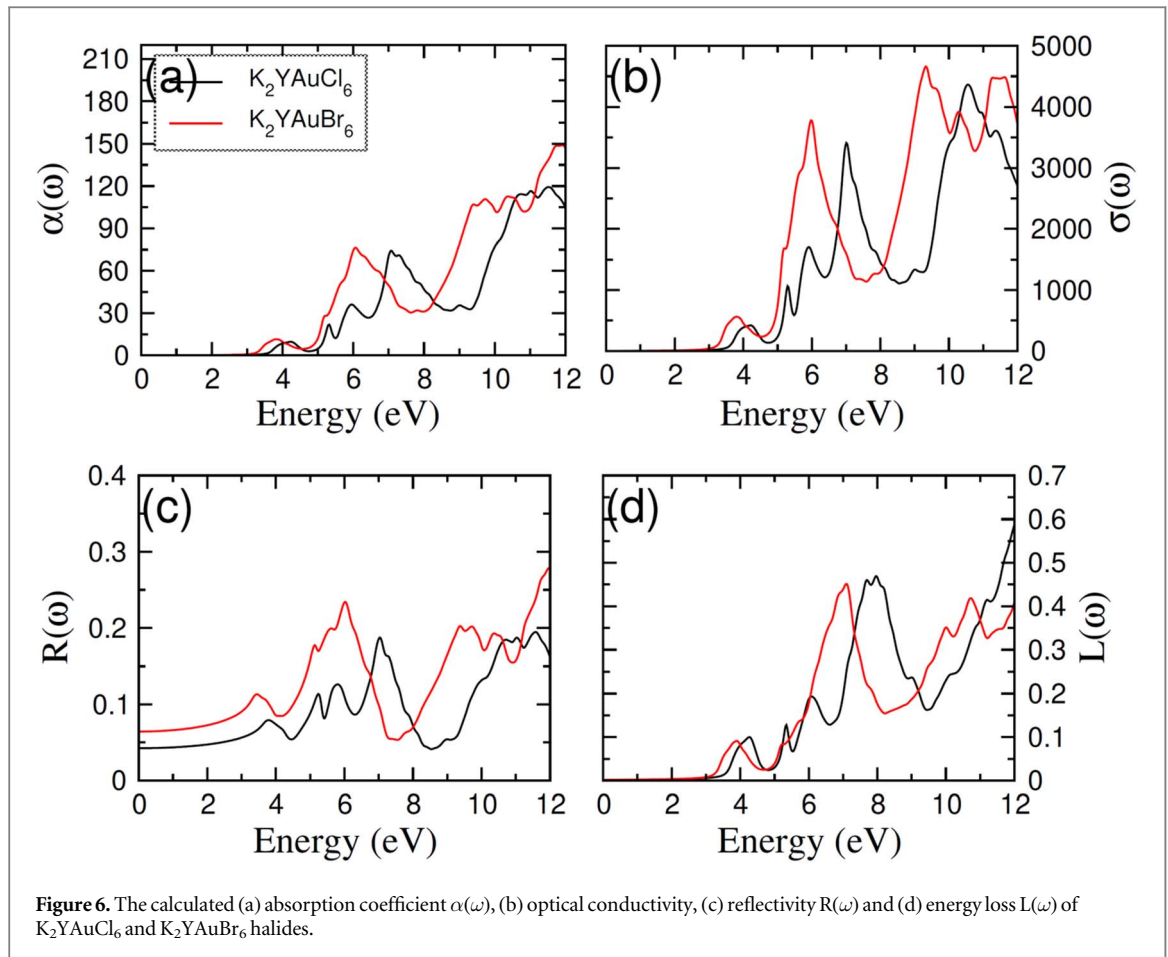


Figure 5. The calculated (a) real part $\epsilon_1(\omega)$, (b) imaginary part $\epsilon_2(\omega)$, (c) refractive index $n(\omega)$, (d) the extinction co-efficient $k(\omega)$ of K_2YAuCl_6 and K_2YAuBr_6 halides.

Table 2. Calculated direct bandgap E_g (eV) values with mBJ potential and optical parameters at 0 energy of K_2YAuCl_6 and K_2YAuBr_6 halides.

Parameters	K_2YAuCl_6	K_2YAuBr_6
	Our work	
E_g (eV)	3.20	2.70
$\epsilon_1(0)$	2.31	2.82
$n(0)$	1.52	1.68
$R(0)$	0.04	0.06

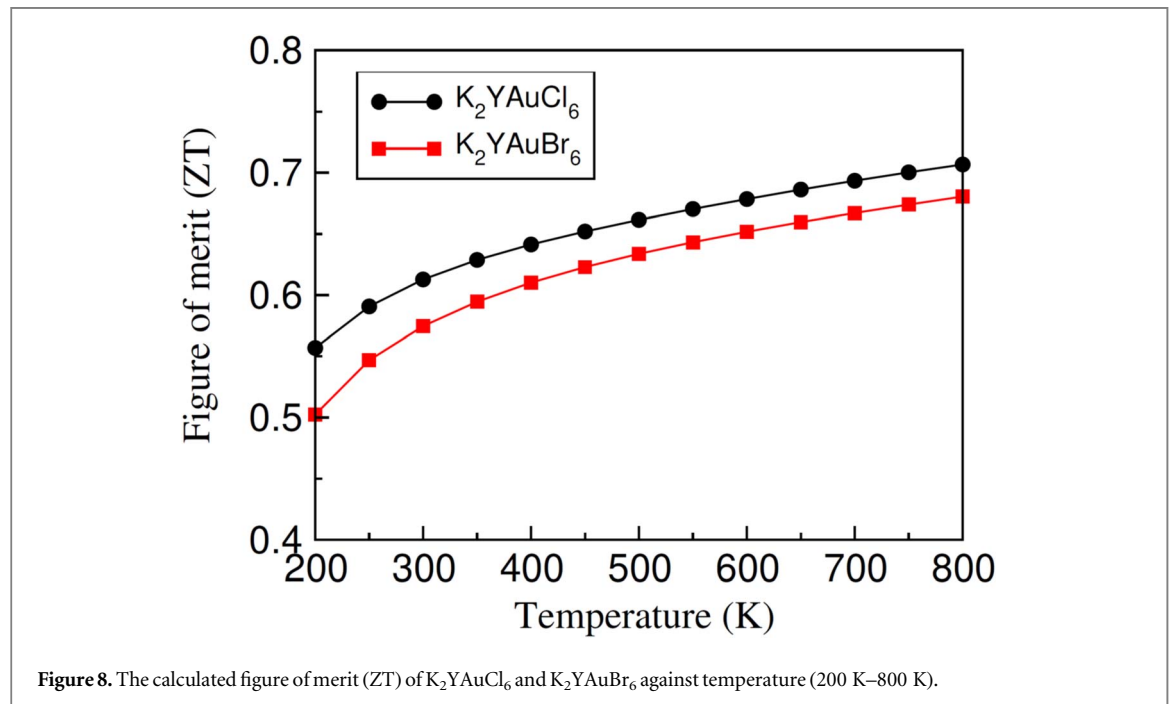
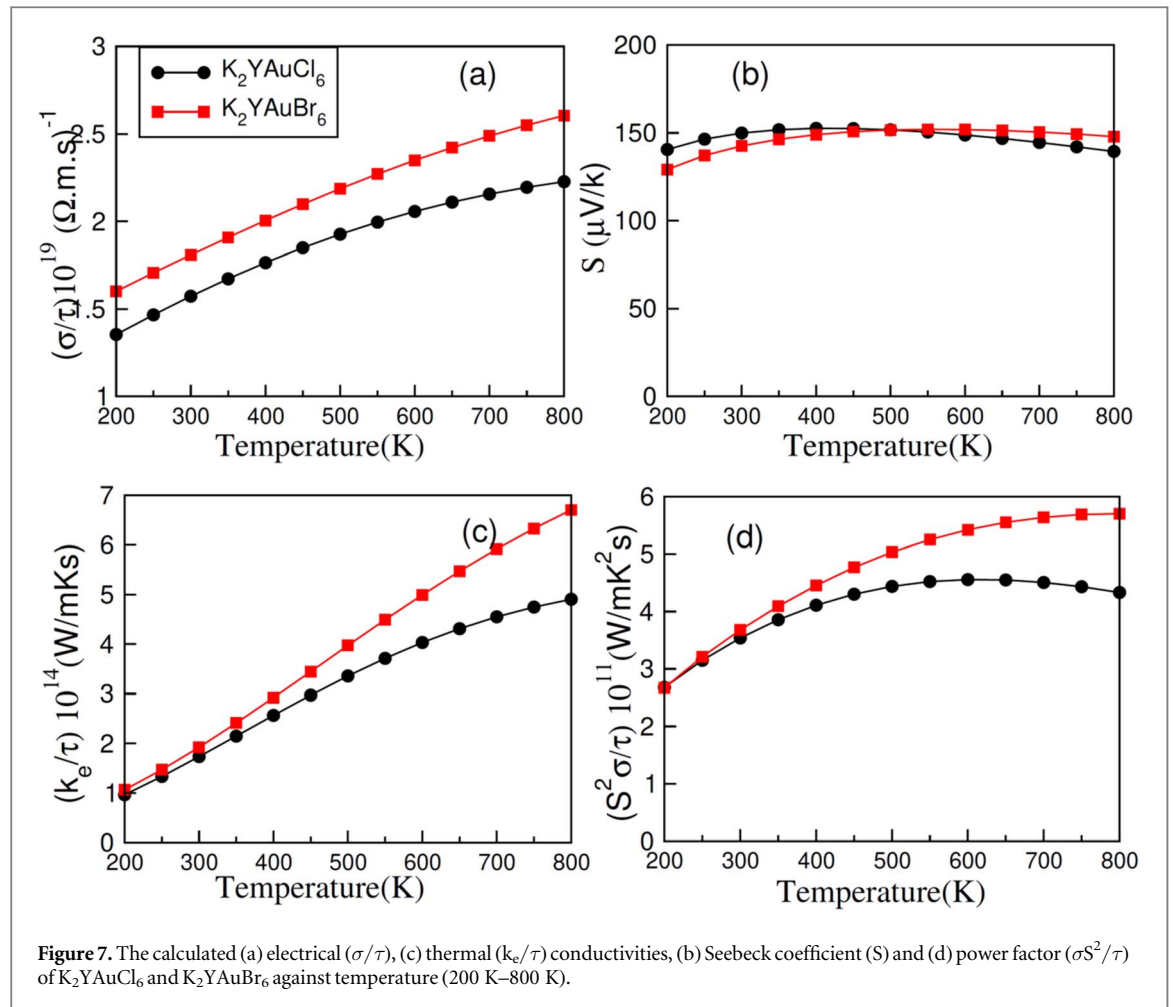
The computation of the total (TDOS) and partial density of states (PDOS) gives a sound insight regarding the participation of different electronic states from various elements to forming electronic bands [53] and plots of TDOS and PDOS are presented in figure 4. This figure revealed that $3p$ -states of K significantly participated in the band formation, extending from -1 to -5 eV for K_2YAuCl_6 and -1 to -4 eV for K_2YAuBr_6 . These states are deep in the conduction band and contribute a relatively small. In addition, $4d$ -states of Y are responsible for band formation and these states appear from 4 to 4.5 eV for K_2YAuCl_6 in the conduction band and slightly shifted towards the Fermi level for K_2YAuBr_6 . These states are the closest to Fermi level in the conduction band and thus formed the conduction band edge. In the case of Au, $5d$ -states are contributing states in band formation, and they effectively do the job in valence band formation. In the valence band, they spread out from the Fermi level to -4.8 eV for K_2YAuCl_6 whereas these states are contracted towards Fermi level with increase of size of halogen. However, maximum density of states is around -0.9 to -1.2 eV. Moving to the halogen revealed that $3p$ and $4p$ -states of Cl and Br actively participated in valence band formation, and these states spread out in a wide energy range from Fermi level to -5.2 eV for K_2YAuCl_6 and Fermi level to -4.8 eV for K_2YAuBr_6 respectively [54].



3.4. Optical characteristics

The optical behavior of any material depends upon the probability of inter-band electronic transitions and their recombination rate as well. The underlying mechanism behind the optical response of materials is the Kramer-Kronig relation which describes how matter reacts on exposure to external radiation [55]. This interaction is quantified in terms of various optical parameters such as real (ε_1) and imaginary (ε_2) parts of the dielectric constant which are plotted in figures 5(a) and (b). The $\varepsilon_1(\omega)$ quantifies the extent of polarization of the material as a result of interaction with radiation. The value of $\varepsilon_1(0)$ is known as the static dielectric constant and its value is found to be 2.31 and 2.82 for K_2YAuCl_6 and K_2YAuBr_6 , respectively. The higher value of $\varepsilon_1(0)$ for Br-based composition indicates that Br-based composition is more polarizable which is because of the higher atomic size of Br as compared to Cl. This is due to the fact that the atomic polarizability is directly proportional to the size of the electronic cloud [56]. Since the size of the Br atom is larger as compared to Cl, this is why Br-based composition revealed higher value of $\varepsilon_1(0)$. Initially, $\varepsilon_1(\omega)$ raised with an increase of energy of interacting light and achieved the first maxima at 3.7 eV, the second maxima at 5.1 eV and these peaks are called relaxation peaks and are used to determine the resonance frequency. For K_2YAuBr_6 , these peaks appeared at slightly lower energy value because of the involvement of heavier element Br as compared to K_2YAuCl_6 . As a matter of fact, heavier masses have low resonance frequency. According to the Penny's model i.e., $\varepsilon_1(0) \approx 1 + (\hbar\omega_p/E_g)^2$, the $\varepsilon_1(0)$ is inversely linked with the bandgap value (E_g) which gives the extra support to the reduction of bandgap value of K_2YAuBr_6 [57].

During the interaction of electromagnetic radiations with matter, some part of the electromagnetic spectrum is absorbed, which is determined by $\varepsilon_2(\omega)$ and its variation is presented in figure 5(b). These spectra also help to determine the E_g value which are consistent with the bandgap values determined through electronic band structures. The peak value of $\varepsilon_2(\omega)$ appeared at 7 eV for K_2YAuCl_6 , which reduced to 6 eV for K_2YAuBr_6 , indicating that these materials are good absorbers for the ultraviolet region and their absorption range is almost constant. The value of refractive index at zero frequency $n(0)$ is linked with $\varepsilon_1(0)$ as $n(0) = \sqrt{\varepsilon_1(0)}$. The value of $n(0)$ for K_2YAuCl_6 and K_2YAuBr_6 are recorded as 1.52, and 1.68, respectively, as shown in table 2. The incidence of light on material's surface results in the multiple signals like reflection, absorption, and scattering. The incident light absorbs if energy of its photon is larger/equal to the material's bandgap, otherwise scatters [58]. In addition, the plot of extinction coefficient $k(\omega)$ shown in figure 5(d), also exhibited multiple peaks with the



highest intensity peak appeared at 7.1 eV for K_2YAuCl_6 , which is red shifted and emerged at 6 eV for K_2YAuBr_6 . The position of these peaks in this graph is identical to the $\varepsilon_2(\omega)$ graph which is presented in part (b).

Absorption coefficient $\alpha(\omega)$ is another key factor which quantifies the amount of energy absorbed per unit length and its variation with energy of incident EM radiation is plotted in figure 6(a) [59]. The high value of $\alpha(\omega)$

Table 3. Comparison of thermoelectric parameters of under study compositions with literature at room temperature.

Compositions	$\sigma/\tau (\times 10^{19}/\Omega\text{ms})$	$\kappa_e/\tau (\times 10^{19}/\Omega\text{ms})$	$S (\mu\text{V/K})$	ZT	References
Rb ₂ YInCl ₆	1.57	0.36	242.35	0.76	[70]
Rb ₂ YInBr ₆	1.53	0.34	234.17	0.74	[70]
K ₂ YAgBr ₆	1.65	1.98	158.48	0.63	[71]
K ₂ YAgI ₆	0.95	1.64	158.48	0.74	[71]
K ₂ YAuCl ₆	1.55	1.80	151.02	0.62	This work
K ₂ YAuBr ₆	1.75	1.95	145.17	0.57	This work

corresponds to better interband electronic transitions [60]. The flow of charge particles in the presence of electromagnetic field is coined as the optical conductivity $\sigma(\omega)$. It varies with frequency of applied field and its variation is presented in figure 6(b). It appeared minimum in the same region of the electromagnetic spectrum where $\alpha(\omega)$ was minimum [61]. Each composition exhibited two high-intensity peaks in the UV region. For K₂YAuCl₆, these peaks appeared at 7.0 eV and 10.5 eV whereas for K₂YAuBr₆, these peaks are red-shifted (towards low energy) and emerged at 6.0 eV and 9.3 eV. The presence of these peaks in UV region stipulates their utilization for optoelectronic devices working in UV regions like Mercury lamps and plasma torches [62]. Interestingly, the height of peaks corresponding to K₂YAuBr₆ spectrum is larger which is due to the larger number of electrons preset in this composition. Figure 6(c) shows the variation of optical reflectivity $R(\omega)$ at zero hertz frequency $R(0)$ and its value is observed as 0.04 and 0.06 for K₂YAuCl₆ and K₂YAuBr₆, respectively [63]. The large value of $R(0)$ for K₂YAuBr₆ is because of the high atomic number and larger electronic density of Br as compared to Cl. During motion inside the material, the energy of electrons decay which is measured by the optical loss function $L(\omega)$, and that is presented in figure 6(d). The peaks in these spectra correspond to the plasma resonance of materials. The phenomenon of collective vibration of valence band electrons is termed as plasma resonance and associated frequency is known as plasma frequency (ω_p) [64]. The significant peaks in $L(\omega)$ appeared in UV region at 8 eV and 7 eV for K₂YAuCl₆ and K₂YAuBr₆ respectively.

3.5. Thermoelectric properties

The concept of Seebeck and Peltier effect emerged back in 19th century which opened new horizons for energy harvesting technology. By their capacity of mutual conversion of thermal and electrical energy thermoelectric materials are capable to revolutionize modern-day technology like semiconductor refrigeration and waste heat recovery. Researchers have always intended to expand the scope and area of applications of thermoelectric materials by improving their thermoelectric efficiency. The thermoelectric efficiency of any material is indexed by the unitless figure of merit (ZT), which is equal to $S^2\sigma T/\kappa$ [65]. The variation of temperature-dependent electrical conductivity (σ/τ) is presented in figure 7(a) in the temperature range of 200–800 K. Here τ represent the relaxation time, and its value lies in the range of 10^{-13} – 10^{-14} s for most semiconducting materials. In the present scenario, for calculating thermoelectric properties, we set its value as 10^{-14} s [66]. At 200 K, the value of σ/τ was recorded as 1.35 and $1.65 \times 10^{19} (\Omega\text{ms})^{-1}$ for K₂YAuCl₆ and K₂YAuBr₆, respectively. With increase of temperature (T), a linear increase in σ/τ was observed and it reached to 2.12 and $2.61 \times 10^{19} (\Omega\text{ms})^{-1}$ at 800 K. In addition to σ/τ , the electronic part of thermal conductivity (κ_e/τ) is plotted in figure 7(c). Since Boltztrap code cannot take into account the lattice part of thermal conductivity κ_l/τ due to which only electronic part was considered here. The value of κ_e/τ was noticed as 1×10^{14} W/mKs for both materials at 200 K and increased with temperature [67]. The rate of increase for K₂YAuBr₆ is greater due to which the value of κ_e/τ for this composition reached to 6.7×10^{14} W mK⁻¹s⁻¹ at 800 K whereas the for K₂YAuCl₆ this value is noticed as 4.8×10^{14} W mK⁻¹s⁻¹. This larger value of κ_e/τ for K₂YAuBr₆ may be due to this composition's greater mobility and high carrier concentration. The calculation of Seebeck coefficient was executed and computed values are plotted in figure 7(b). The positive value of S indicates the presence of positive charge carriers. In the studied range of temperature, S varied slightly in the 130–150 $\mu\text{V K}^{-1}$ range. For potentially active thermoelectric materials, the value of S lies in the range of 200 $\mu\text{V K}^{-1}$ [68]. Thermoelectric materials' efficiency is mapped by calculating the value of power factor (PF) or figure of merit (ZT). These two parameters differ from each other on the basis of the inclusion or exclusion of thermal conductivity. PF estimates the conversion efficiency without taking into account κ/τ whereas ZT take its effect, this is why efficiency determined by the ZT is more accurate as compared with PF. The calculated value of PF is plotted in figure 7(d), having value 2.7×10^{11} W mK²s at 200 K for both compositions and increased to 4.4×10^{11} and 5.7×10^{11} W mK²s at 800 K for K₂YAuCl₆ and K₂YAuBr₆ respectively. The most significant parameter in the estimation of the thermoelectric response of the material is ZT which is expressed in figure 8. Its value was noticed as 0.55 and 0.50 at 200 K and .71 and 0.68 at 800 K for K₂YAuCl₆ and K₂YAuBr₆ respectively. This trend of this graph shows that the value of ZT can further be

improved by increasing the temperature, making these compositions suitable for high-temperature applications [69]. A comparison of thermoelectric parameters of different double perovskites is presented in the table 3.

4. Conclusion

In nutshell, we elaborated here the structural, optical, electronic, and transport properties of K_2YAuX_6 ($X = Cl, Br$) double perovskites using the WIEN2K code. In this study, the structure was first relaxed to determine the optimized lattice parameters and ground state energy. The computation of elastic constants, modulus of elasticity, and Poisson's (>0.26) and Pugh (>1.75) ratios confirmed their ductile nature. The electronic band structure revealed the in-direct bandgap nature with bandgap values of 3.20 eV and 2.82 eV for K_2YAuCl_6 and K_2YAuBr_6 respectively. The analysis of the total density of states and partial density of states provided a clear picture regarding the contribution of various states of involving atoms. The presence of multiple peaks in UV region for dielectric constant, refractive index, optical conductivity, and absorption spectra gave a clue about the range of applicability of these compositions. The high value of the Wiedemann–Franz ratio, large electrical conductivity, and Seebeck coefficient with a small value of thermal conductivity highlighted the importance of these compositions for futuristic thermoelectric devices.

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Data availability statement

All data that support the findings of this study are included within the article (and any supplementary files).

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